## NSN 5961-01-464-7729

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-7729 **Inclosure Material:** Glass **Overall Length:** 8.900 millimeters **Terminal Length:** 2.550 millimeters **End Application:** Rsip pple/ifscm97942 **Mounting Facility Quantity: Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -12.0 breakdown voltage, collector-to-emitter, base open and -20.0 collector to base voltage/static/emitter open and -3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -50.00 milliamperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Aircraft, awacse-3a **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: